74AUP1G126

Low-power buffer/line driver; 3-state

Rev. 9 — 14 January 2022

Product data sheet

1. General description

The 74AUP1G126 provides a single non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (OE). A LOW level at pin OE causes the output to assume a high-impedance OFF-state. This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input OE is LOW.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Low-power buffer/line driver; 3-state

3. Ordering information

Table 1. Ordering information

Type number	Package						
	Temperature range	Name	Description	Version			
74AUP1G126GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1			
74AUP1G126GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886			
74AUP1G126GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115			
74AUP1G126GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202			
74AUP1G126GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3			

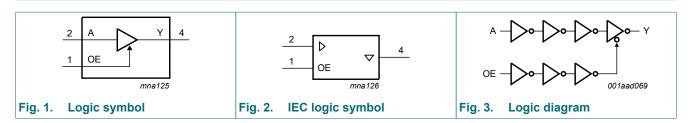
4. Marking

Table 2. Marking

Table 21 Marking					
Marking code[1]					
pN					

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

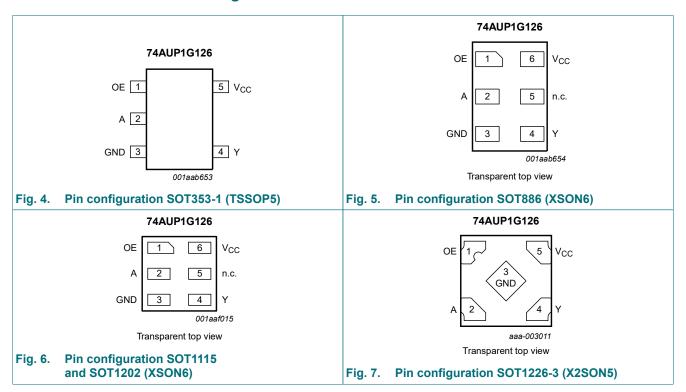


Product data sheet

Low-power buffer/line driver; 3-state

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
	TSSOP5 and X2SON5	XSON6	
OE	1	1	output enable input
A	2	2	data input
GND	3	3	ground (0 V)
Υ	4	4	data output
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = Don't care; Z = high-impedance OFF-state.

Input OE		Output
OE	A	Υ
Н	L	L
Н	Н	Н
L	X	Z

74AUP1G126

Low-power buffer/line driver; 3-state

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode [1]	-0.5	V _{CC} + 0.5	V
		Power-down mode; V _{CC} = 0 V [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

^[2] For SOT353-1 (TSSOP5) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

Low-power buffer/line driver; 3-state

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
	LOW-level input voltage HIGH-level output voltage	V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 V$ to 3.6 V; $V_{CC} = 0 V$	-	-	±0.2	μΑ
ΔI _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$ to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	data input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; [1] $V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
		OE input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; [1] $V_{CC} = 3.3 \text{ V}$	-	-	110	μΑ
		all inputs; V_1 = GND to 3.6 V; OE = GND; [2] V_{CC} = 0.8 V to 3.6 V	-	-	1	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.9	-	pF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_O = GND or V_{CC}	-	1.5	-	pF
T _{amb} = -4	40 °C to +85 °C				ı	
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	V _I = V _{IH} or V _{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 V$ to 3.6 V; $V_{CC} = 0 V$	-	-	±0.5	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.6	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μΑ
ΔI _{CC}	additional supply current	data input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; [1] $V_{CC} = 3.3 \text{ V}$	-	-	50	μΑ
		OE input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; [1] $V_{CC} = 3.3 \text{ V}$	-	-	120	μΑ
		all inputs; V_I = GND to 3.6 V; OE = GND; [2] V_{CC} = 0.8 V to 3.6 V	-	-	1	μΑ
T _{amb} = -4	40 °C to +125 °C				l.	
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V_{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V_{OL}	LOW-level output	V _I = V _{IH} or V _{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V		-	-	±0.75	μΑ
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	-	±0.75	μΑ
ΔI_{OFF}	additional power-off leakage current	V_1 or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$ to 0.2 V		-	-	±0.75	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V		-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	1]	-	-	75	μΑ
		OE input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	1]	-	-	180	μΑ
		all inputs; V_I = GND to 3.6 V; OE = GND; [2 V_{CC} = 0.8 V to 3.6 V	2]	-	-	1	μΑ

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = 2	5 °C; C _L = 5 pF					
t _{pd}	propagation delay	A to Y; see <u>Fig. 8</u> [2]				
		V _{CC} = 0.8 V	-	20.6	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	4.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	ns
t _{en}	enable time	OE to Y; see Fig. 9 [3]				
		V _{CC} = 0.8 V	-	71.6	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.2	12.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.2	6.9	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.3	5.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.4	3.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.0	2.9	ns
t _{dis}	disable time	OE to Y; see Fig. 9 [4]				
		V _{CC} = 0.8 V	-	10.3	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	4.2	6.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.1	4.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.4	3.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	2.8	3.6	ns

^[2] To show I_{CC} remains very low when the input-disable feature is enabled.

Low-power buffer/line driver; 3-state

- -		Conditions	Min	Typ[1]	Max	Unit
I _{amb} =	25 °C; C _L = 10 pF		1			
t _{pd}	propagation delay	see <u>Fig. 8</u> [2]				
		V _{CC} = 0.8 V	-	24.0	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	ns
t _{en}	enable time	see <u>Fig. 9</u> [3]				
		V _{CC} = 0.8 V	-	75.3	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.1	14.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.8	8.0	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.9	5.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.9	4.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.6	3.6	ns
t _{dis} d	disable time	see <u>Fig. 9</u> [4]				
		V _{CC} = 0.8 V	-	12.2	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	5.3	7.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.4	4.2	5.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.2	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	4.1	5.0	ns
T _{amb} =	25 °C; C _L = 15 pF					
t _{pd}	propagation delay	see <u>Fig. 8</u> [2]				
•		V _{CC} = 0.8 V	-	27.4	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.2	14.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	ns
t _{en}	enable time	see <u>Fig. 9</u> [3]				
OII		V _{CC} = 0.8 V	-	79.2	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.8	15.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.4	8.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	4.3	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	3.1	4.3	ns
t _{dis}	disable time	see Fig. 9 [4]				
uio		V _{CC} = 0.8 V	-	14.9	_	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.4	8.5	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	3.0	5.0	6.6	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	5.4	6.6	ns
		V_{CC} = 2.3 V to 2.7 V	2.4	4.0	5.0	ns

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = 2	25 °C; C _L = 30 pF					
t _{pd}	propagation delay	see Fig. 8	2]			
		V _{CC} = 0.8 V	-	37.4	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	18.7	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	10.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	5.8	ns
t _{en}	enable time	see Fig. 9	3]			
		V _{CC} = 0.8 V	-	90.6	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.7	10.0	20.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	6.9	11.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.6	8.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.5	6.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	4.2	5.8	ns
t _{dis}	disable time	see Fig. 9	4]			
		V _{CC} = 0.8 V	-	51.6	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.8	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	4.5	7.7	10.5	ns
		V _{CC} = 1.65 V to 1.95 V	5.2	8.8	11.4	ns
		V _{CC} = 2.3 V to 2.7 V	3.9	6.4	7.4	ns
		V _{CC} = 3.0 V to 3.6 V	5.5	9.0	10.7	ns
T _{amb} = 2	25 °C			1		
C _{PD}	power dissipation capacitance	$f = 1 \text{ MHz}$; $V_I = \text{GND to } V_{CC}$; output enabled	5]			
		V _{CC} = 0.8 V	-	2.7	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	pF

- [1] All typical values are measured at nominal V_{CC} .
- t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] [3] t_{en} is the same as t_{PZH} and t_{PZL} .
- [4] t_{dis} is the same as t_{PHZ} and t_{PLZ}.
 [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} × V_{CC}² × f_i × N + Σ(C_L × V_{CC}² × f_o) where:

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Low-power buffer/line driver; 3-state

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
C _L = 5 p	F				<u>'</u>	<u>'</u>	
t _{pd}	propagation delay	A to Y; see <u>Fig. 8</u> [1]					
		V _{CC} = 1.1 V to 1.3 V	2.5	11.7	2.5	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.0	7.3	2.0	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	6.1	1.7	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	4.3	1.4	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.2	3.9	1.2	4.4	ns
t _{en}	enable time	OE to Y; see Fig. 9 [2]					
		V _{CC} = 1.1 V to 1.3 V	2.6	13.6	2.6	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	7.4	2.2	7.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	5.9	1.7	6.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	3.8	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.2	3.2	1.2	3.4	ns
t _{dis}	disable time	OE to Y; see Fig. 9 [3]					
		V _{CC} = 1.1 V to 1.3 V	2.9	6.4	2.9	6.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	2.2	4.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	4.6	1.7	4.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	3.4	1.4	3.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.2	3.7	1.2	3.8	ns
C _L = 10	pF						
t _{pd}	propagation delay	A to Y; see <u>Fig. 8</u> [1]					T
		V _{CC} = 1.1 V to 1.3 V	3.0	13.8	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.9	8.5	1.9	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	6.8	1.7	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	5.3	1.6	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	4.6	1.6	5.2	ns
t _{en}	enable time	OE to Y; see Fig. 9 [2]					
		V _{CC} = 1.1 V to 1.3 V	3.0	15.4	3.0	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	8.3	2.1	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	6.5	1.7	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	4.5	1.4	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	3.8	1.3	4.0	ns
t _{dis}	disable time	OE to Y; see Fig. 9 [3]					
		V _{CC} = 1.1 V to 1.3 V	3.3	7.9	3.3	7.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	5.7	2.1	5.9	ns
		V _{CC} = 1.65 V to 1.95 V	1.7	5.8	1.7	6.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	4.3	1.4	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	5.2	1.3	5.3	ns

Low-power buffer/line driver; 3-state

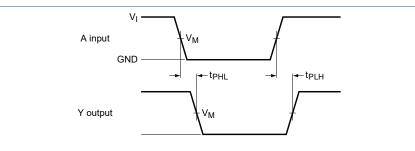
Symbol	Parameter	Conditions		-40 °C to +85 °C		-40 °C to +125 °C		Unit
				Min	Max	Min	Max	
C _L = 15	pF							
t _{pd} propagation delay		A to Y; see Fig. 8	[1]					
		V _{CC} = 1.1 V to 1.3 V		3.3	15.8	3.3	17.5	ns
		V _{CC} = 1.4 V to 1.6 V		2.5	9.8	2.5	10.9	ns
		V _{CC} = 1.65 V to 1.95 V		2.0	7.9	2.0	8.8	ns
		V _{CC} = 2.3 V to 2.7 V		1.8	6.0	1.8	6.7	ns
		V _{CC} = 3.0 V to 3.6 V		1.8	5.4	1.8	6.1	ns
t _{en}	enable time	OE to Y; see Fig. 9	[2]					
		V _{CC} = 1.1 V to 1.3 V		3.3	17.1	3.3	17.1	ns
		V _{CC} = 1.4 V to 1.6 V		2.9	9.4	2.9	9.7	ns
		V _{CC} = 1.65 V to 1.95 V		2.0	7.3	2.0	7.7	ns
		V _{CC} = 2.3 V to 2.7 V		1.7	5.2	1.7	5.6	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	4.5	1.5	4.7	ns
t _{dis}	disable time	OE to Y; see Fig. 9	[3]					
		V _{CC} = 1.1 V to 1.3 V		3.7	9.3	3.7	9.4	ns
		V _{CC} = 1.4 V to 1.6 V		2.5	6.9	2.5	7.0	ns
		V _{CC} = 1.65 V to 1.95 V		2.0	7.4	2.0	7.5	ns
		V _{CC} = 2.3 V to 2.7 V		1.7	5.1	1.7	5.5	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	6.7	1.5	6.9	ns
C _L = 30	pF						'	
t _{pd}	propagation delay	A to Y; see Fig. 8	[1]					
		V _{CC} = 1.1 V to 1.3 V		4.4	21.4	4.4	24.0	ns
		V _{CC} = 1.4 V to 1.6 V		3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	10.3	2.6	11.5	ns
		V _{CC} = 2.3 V to 2.7 V		2.5	7.8	2.5	8.7	ns
		V _{CC} = 3.0 V to 3.6 V		2.5	7.0	2.5	8.3	ns
t _{en}	enable time	OE to Y; see Fig. 9	[2]					
		V _{CC} = 1.1 V to 1.3 V		4.3	22.0	4.3	22.0	ns
		V _{CC} = 1.4 V to 1.6 V		3.7	12.0	3.7	12.5	ns
		V _{CC} = 1.65 V to 1.95 V		3.2	9.5	3.2	10.1	ns
		V _{CC} = 2.3 V to 2.7 V		2.9	6.8	2.9	7.3	ns
		V _{CC} = 3.0 V to 3.6 V		2.7	6.4	2.7	6.7	ns
t _{dis}	disable time	OE to Y; see Fig. 9	[3]					
		V _{CC} = 1.1 V to 1.3 V		4.7	14.3	4.7	14.4	ns
		V _{CC} = 1.4 V to 1.6 V		3.0	10.7	3.0	11.0	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	11.5	2.6	11.6	ns
		V _{CC} = 2.3 V to 2.7 V		2.3	9.0	2.3	10.2	ns
		V _{CC} = 3.0 V to 3.6 V		2.2	10.8	2.2	12.0	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 t_{en} is the same as t_{PZH} and t_{PZL} . t_{dis} is the same as t_{PHZ} and t_{PLZ} .

Low-power buffer/line driver; 3-state

11.1. Waveforms and test circuit

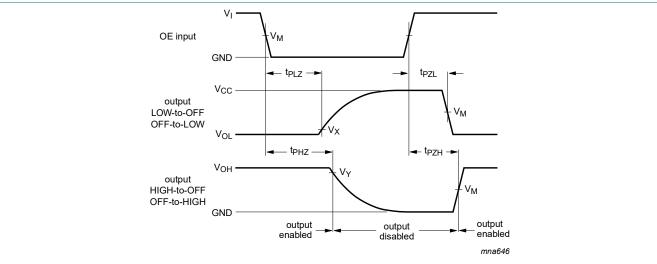


001aad070

Measurement points are given in Table 10.

Logic levels: V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 8. The data input (A) to output (Y) propagation delays



Measurement points are given in <u>Table 10</u>.

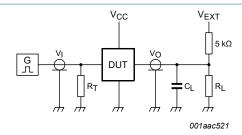
Logic levels: V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 9. Enable and disable times

Table 10. Measurement points

Supply voltage	Input			Output	Output			
V _{CC}	V _M	V _I	$t_r = t_f$	V _M	V _X	V _Y		
0.8 V to 1.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V		
1.65 V to 2.7 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V		
3.0 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		

Low-power buffer/line driver; 3-state



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 10. Test circuit for measuring switching times

Table 11. Test data

Supply voltage Load		V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

Product data sheet

Low-power buffer/line driver; 3-state

12. Package outline

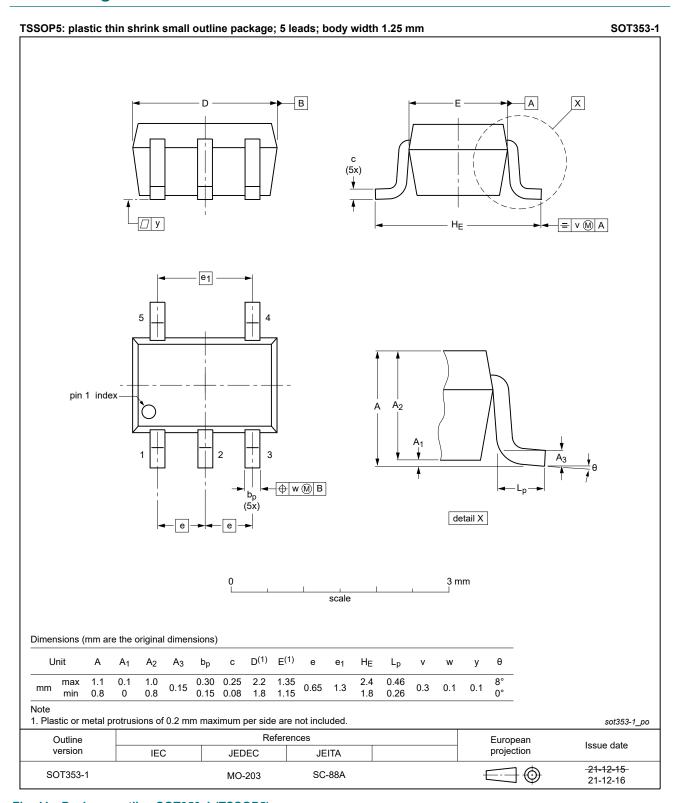


Fig. 11. Package outline SOT353-1 (TSSOP5)

Low-power buffer/line driver; 3-state

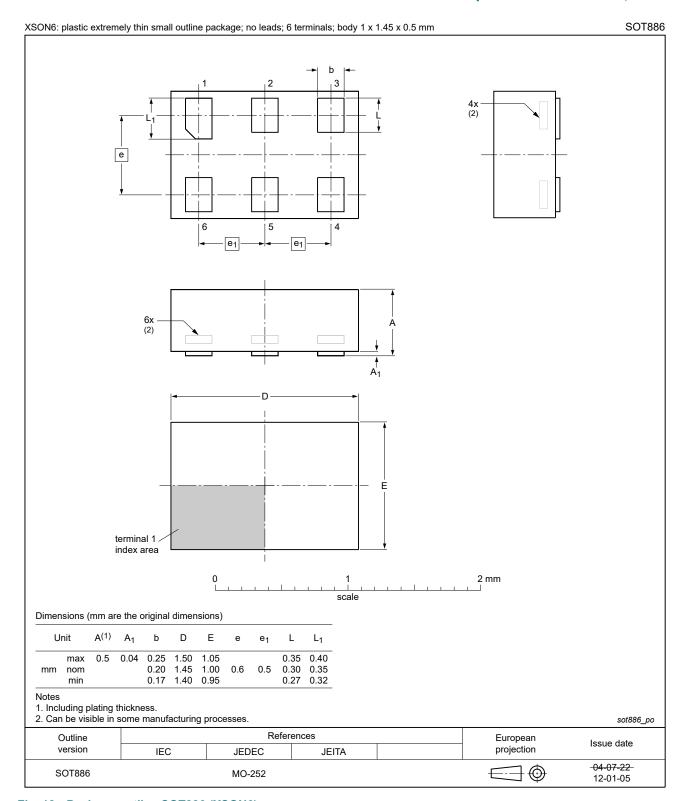


Fig. 12. Package outline SOT886 (XSON6)

Low-power buffer/line driver; 3-state

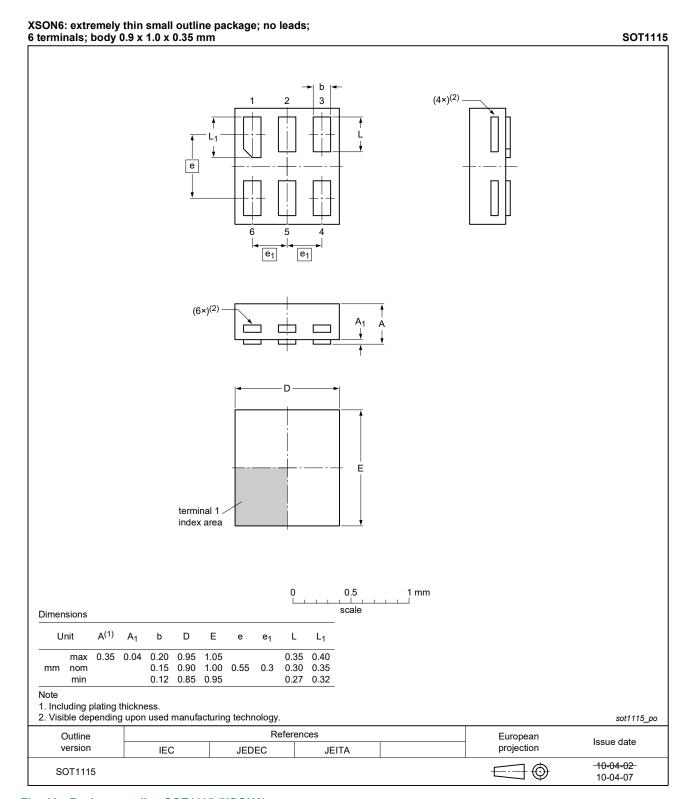


Fig. 13. Package outline SOT1115 (XSON6)

Low-power buffer/line driver; 3-state

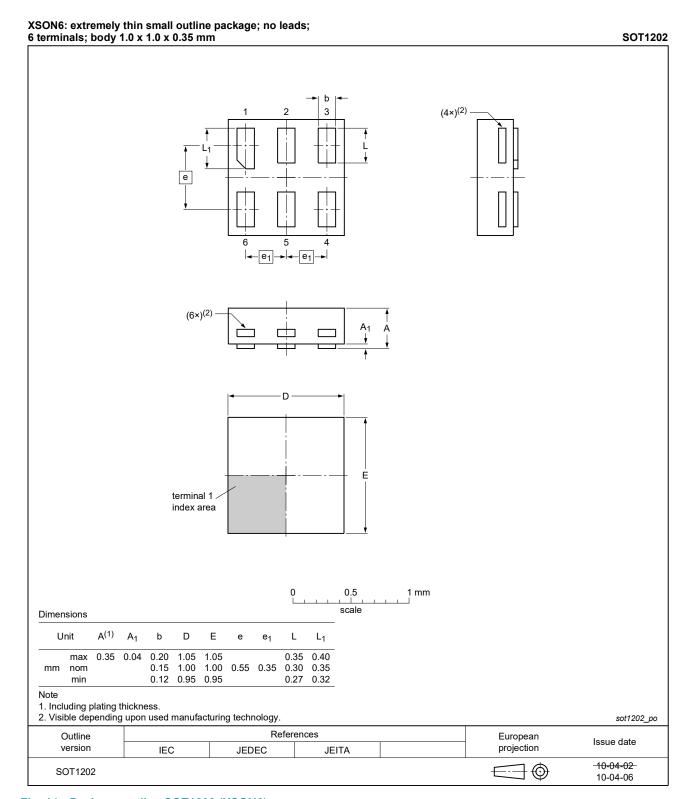


Fig. 14. Package outline SOT1202 (XSON6)

Low-power buffer/line driver; 3-state

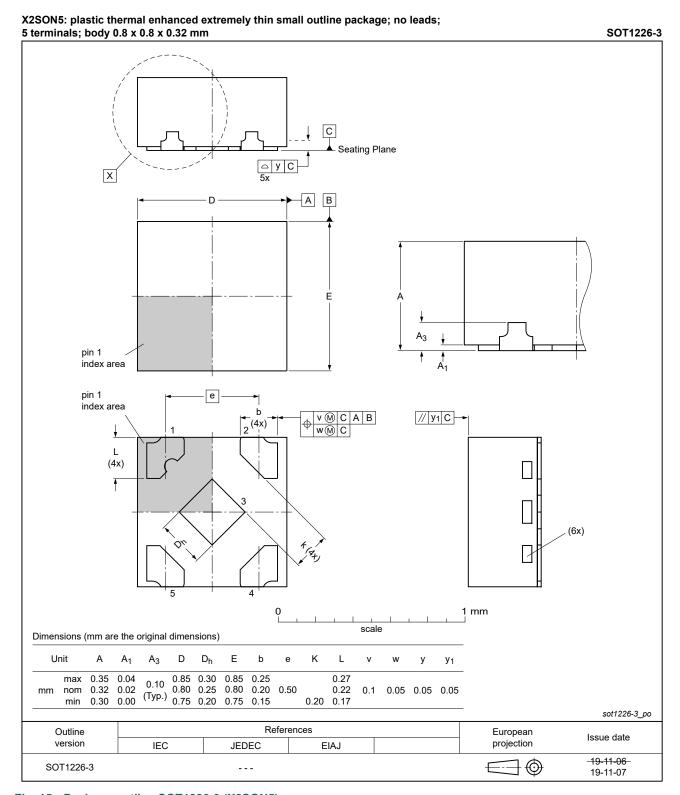


Fig. 15. Package outline SOT1226-3 (X2SON5)

Low-power buffer/line driver; 3-state

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP1G126 v.9	20220114	Product data sheet	-	74AUP1G126 v.8			
Modifications:	Fig. 11: Package outline drawing for SOT353-1 (TSSOP5) has changed.						
74AUP1G126 v.8	20210430	210430 Product data sheet - 74AUP1G126 v.7					
Modifications:	 SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package. Type number 74AUP1G126GF (SOT891) removed. Table 5: Derating values for P_{tot} total power dissipation updated. 						
74AUP1G126 v.7	20180516	Product data sheet	-	74AUP1G126 v.6			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 						
74AUP1G126 v.6	20151002	Product data sheet	-	74AUP1G126 v.5			
Modifications:	• I _{OK} minimun	n changed from -0.5 mA to	-50 mA (errata) ir	Table 5			
74AUP1G126 v.5	20120628	Product data sheet	-	74AUP1G126 v.4			
Modifications:	 Added type number 74AUP1G126GX (SOT1226) Package outline drawing of SOT886 (Fig. 12) modified. 						
74AUP1G126 v.4	20111124	Product data sheet	-	74AUP1G126 v.3			
74AUP1G126 v.3	20100903	Product data sheet	-	74AUP1G126 v.2			
74AUP1G126 v.2	20060628	Product data sheet	-	74AUP1G126 v.1			
74AUP1G126 v.1	20050725	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Low-power buffer/line driver; 3-state

Contents

1. General description	1
2. Features and benefits	1
3. Ordering information	2
4. Marking	
5. Functional diagram	
6. Pinning information	
6.1. Pinning	
6.2. Pin description	3
7. Functional description	3
8. Limiting values	4
9. Recommended operating conditions	4
10. Static characteristics	5
11. Dynamic characteristics	
11.1. Waveforms and test circuit	13
12. Package outline	
13. Abbreviations	20
14. Revision history	
15. Legal information	
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